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Yönetilen Tezler

2024	Aydemir U., Yüksek Lisans, A.DURMAZ(Öğrenci), TRAFYO YAĞINDA BOZULMA TESPİTİ İÇİN FİBER OPTİK SENSÖR TASARIMI
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2023	Aydemir U., Yüksek Lisans, Y.KEREM(Öğrenci), İki boyutlu T1GaSe2 ve T1InS2 katkılı ince film fotodiyotların üretilmesi ve incelenmesi
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- IX. **Use of 2D In2Se3 Single Crystal as a Diaphragm Material for Fabry-Perot Fiber Optic Acoustic Sensors**
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- XXI. **Temperature-dependent profile of the surface states and series resistance in (Ni/Au)/AlGaN/AlN/GaN heterostructures**
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- I. **50 GHz, 100 fs pulses at 100 W average power from a burst mode, all-single mode, Yb-doped fiber laser system**
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